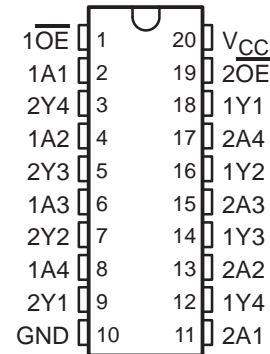


SN74LVCZ240A OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES273B – JUNE 1999 – REVISED JANUARY 2000

- **EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process**
- **Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$**
- **Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$**
- **I_{off} and Power-Up 3-State Support Hot Insertion**
- **Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **Package Options Include Shrink Small-Outline (DB), Plastic Thin Very Small-Outline (DGV), Small-Outline (DW), and Thin Shrink Small-Outline (PW) Packages**

DB, DGV, DW, OR PW PACKAGE
(TOP VIEW)



description

This octal buffer/driver is designed for 2.7-V to 3.6-V V_{CC} operation.

The SN74LVCZ240A is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

This device is organized as two 4-bit buffers/drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN74LVCZ240A is characterized for operation from -40°C to 85°C .



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

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SN74LVCZ240A

OCTAL BUFFER/DRIVER

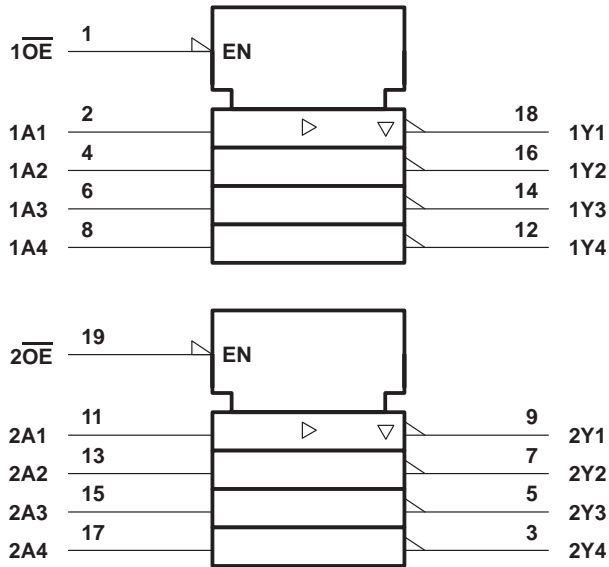
WITH 3-STATE OUTPUTS

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FUNCTION TABLE
(each buffer)

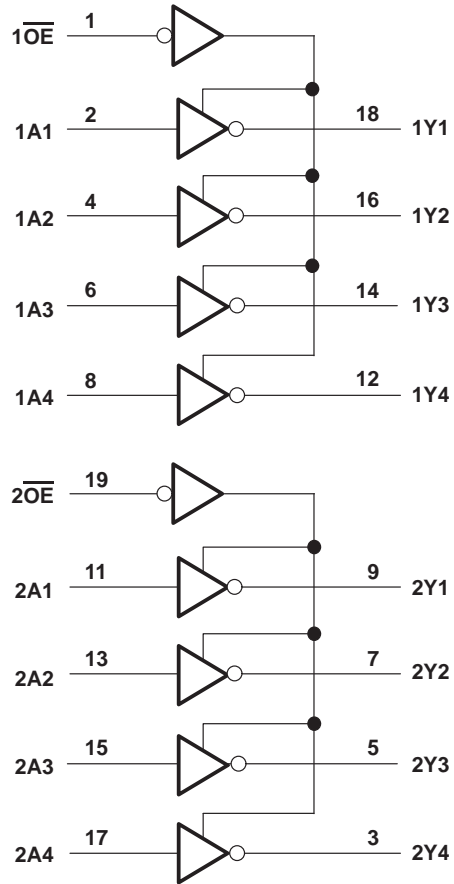
INPUTS		OUTPUT
\overline{OE}	A	Y
L	H	L
L	L	H
H	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



SN74LVCZ240A
OCTAL BUFFER/DRIVER
WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	–0.5 V to 6.5 V
Input voltage range, V_I (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, V_O (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Continuous output current, I_O	±50 mA
Continuous current through V_{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DB package	115°C/W
DGV package	146°C/W
DW package	97°C/W
PW package	128°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The value of V_{CC} is provided in the recommended operating conditions table.
3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	2.7	3.6	V
V_{IH}	High-level input voltage	$V_{CC} = 2.7$ V to 3.6 V		V
V_{IL}	Low-level input voltage	$V_{CC} = 2.7$ V to 3.6 V		V
V_I	Input voltage	0	5.5	V
V_O	Output voltage	High or low state	0	V_{CC}
		3-state	0	5.5
I_{OH}	High-level output current	$V_{CC} = 2.7$ V	–12	
		$V_{CC} = 3$ V	–24	
I_{OL}	Low-level output current	$V_{CC} = 2.7$ V	12	
		$V_{CC} = 3$ V	24	
$\Delta t/\Delta v$	Input transition rise or fall rate	6		ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	150		µs/V
T_A	Operating free-air temperature	–40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SN74LVCZ240A

OCTAL BUFFER/DRIVER

WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP†	MAX	UNIT
V _{OH}	I _{OH} = -100 μA	2.7 V to 3.6 V	V _{CC} -0.2			V
	I _{OH} = -12 mA	2.7 V	2.2			
		3 V	2.4			
	I _{OH} = -24 mA	3 V	2.2			
V _{OL}	I _{OL} = 100 μA	2.7 V to 3.6 V			0.2	V
	I _{OL} = 12 mA	2.7 V			0.4	
	I _{OL} = 24 mA	3 V			0.55	
I _I	V _I = 0 to 5.5 V	3.6 V			±5	μA
I _{off}	V _I or V _O = 5.5 V	0			±5	μA
I _{OZ}	V _O = 0 to 5.5 V	3.6 V			±5	μA
I _{OZPU}	V _O = 0.5 to 2.5 V, \overline{OE} = don't care	0 to 1.5 V			±5	μA
I _{OZPD}	V _O = 0.5 to 2.5 V, \overline{OE} = don't care	1.5 V to 0			±5	μA
I _{CC}	V _I = V _{CC} or GND	3.6 V			100	μA
	3.6 V ≤ V _I ≤ 5.5 V‡				100	
ΔI _{CC}	One input at V _{CC} - 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V			100	μA
C _i	V _I = V _{CC} or GND	3.3 V			3.5	pF
C _o	V _O = V _{CC} or GND	3.3 V			5.5	pF

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

‡ This applies in the disabled state only.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A	7.5		1.3	6.5	ns
t _{en}	\overline{OE}	A or B	9		1.1	8	ns
t _{dis}	\overline{OE}	A or B	8		1.4	7	ns

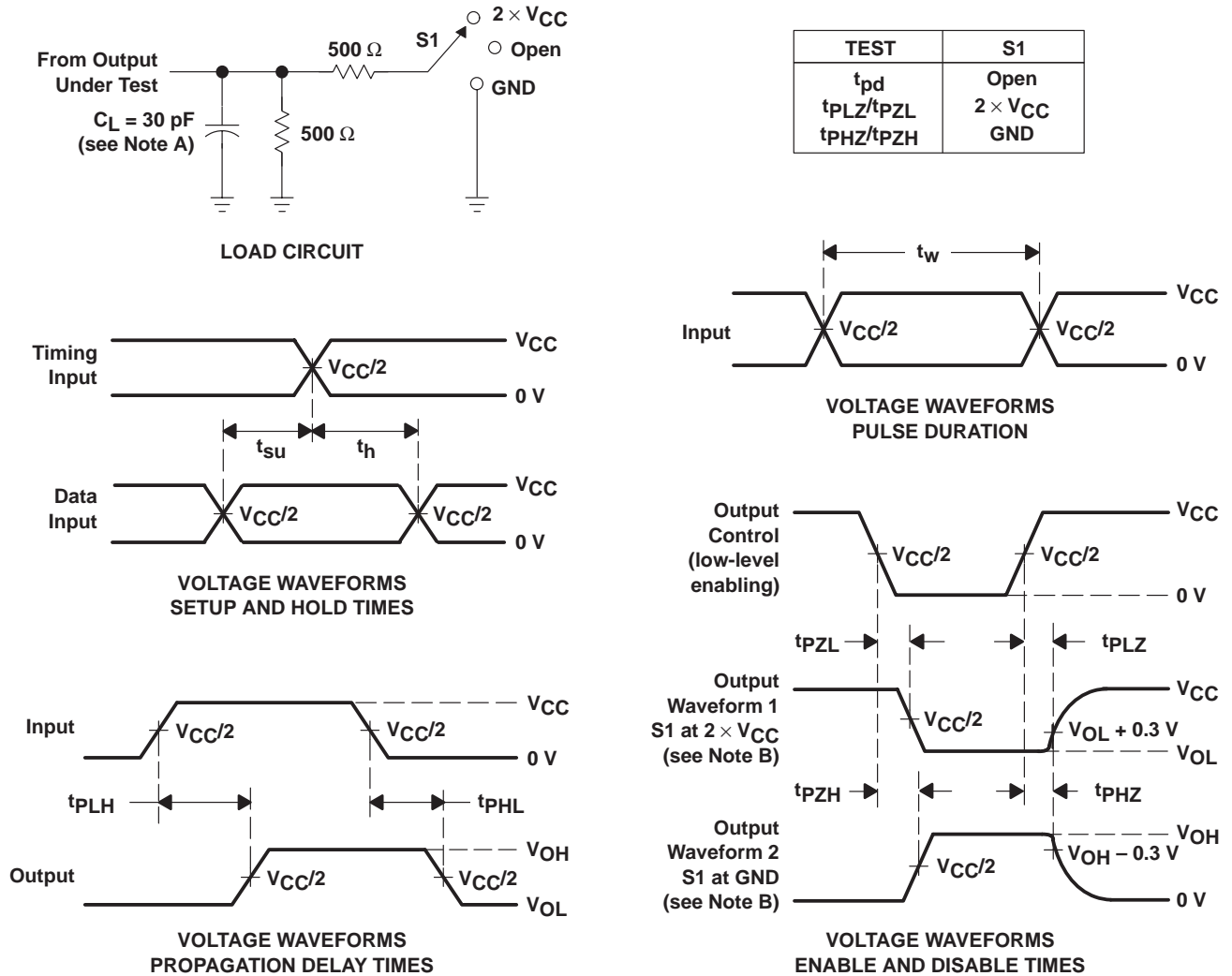
operating characteristics, T_A = 25°C

PARAMETER		TEST CONDITIONS	V _{CC} = 3.3 V TYP	UNIT
C _{pd}	Power dissipation capacitance per buffer/driver	Outputs enabled	37	pF
		Outputs disabled	3	



PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7\text{ V AND } 3.3\text{ V} \pm 0.3\text{ V}$



- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: PRR $\leq 10\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 2\text{ ns}$, $t_f \leq 2\text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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SN74LVCZ240A, Octal Buffer/Driver With 3-State Outputs

DEVICE STATUS: **ACTIVE**

FEATURES

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- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V_{OLP} (Output Ground Bounce) $< 0.8\text{ V}$ at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$
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DESCRIPTION

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The SN74LVCZ240A is characterized for operation from -40°C to 85°C.

TECHNICAL DOCUMENTS

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DATASHEET

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- [CMOS Power Consumption and CPD Calculation](#) (SCAA035B - Updated: 06/01/1997)
- [Implications of Slow or Floating CMOS Inputs](#) (SCBA004C - Updated: 02/01/1998)
- [Input and Output Characteristics of Digital Integrated Circuits](#) (SDYA010 - Updated: 10/01/1996)
- [LVC Characterization Information](#) (SCBA011 - Updated: 12/01/1996)
- [Live Insertion](#) (SDYA012 - Updated: 10/01/1996)
- [Low-Voltage Logic \(LVC\) Designer's Guide](#) (SCBA010 - Updated: 09/01/1996)
- [Migration From 3.3-V To 2.5-V Power Supplies For Logic Devices](#) (SCEA005 - Updated: 12/01/1997)
- [Understanding Advanced Bus-Interface Products Design Guide](#) (SCAA029, 253 KB - Updated: 05/01/1996)

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- [Logic Selection Guide Second Half 2000](#) (SDYU001N, 5035 KB - Updated: 04/17/2000)
- [MicroStar Junior BGA Design Summary](#) (SCET004, 167 KB - Updated: 07/28/2000)
- [More Power In Less Space - Technical Article](#) (SCAU001A, 850 KB - Updated: 03/01/1996)

SAMPLES

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ORDERABLE DEVICE	PACKAGE	PINS	TEMP (°C)	STATUS	SAMPLES
SN74LVCZ240ADBR	DB	20	-40 TO 85	ACTIVE	Request Samples

SN74LVCZ240ADGVR	<u>DGV</u>	20	-40 TO 85	ACTIVE	Request Samples
SN74LVCZ240ADWR	<u>DW</u>	20	-40 TO 85	ACTIVE	Request Samples
SN74LVCZ240APWR	<u>PW</u>	20	-40 TO 85	ACTIVE	Request Samples

PRICING/AVAILABILITY[▲ Back to Top](#)

<u>ORDERABLE DEVICE</u>	<u>PACKAGE</u>	<u>PINS</u>	<u>TEMP (°C)</u>	<u>STATUS</u>	<u>BUDGETARY PRICE US\$/UNIT QTY=1000+</u>	<u>PACK QTY</u>	<u>PRICING/AVAILABILITY</u>
SN74LVCZ240ADBR	<u>DB</u>	20	-40 TO 85	ACTIVE	0.59	2000	Check stock or order
SN74LVCZ240ADGVR	<u>DGV</u>	20	-40 TO 85	ACTIVE	0.67	2000	Check stock or order
SN74LVCZ240ADW	<u>DW</u>	20	-40 TO 85	ACTIVE	0.59	25	Check stock or order
SN74LVCZ240ADWR	<u>DW</u>	20	-40 TO 85	ACTIVE	0.59	2000	Check stock or order
SN74LVCZ240AN	<u>N</u>	20	-40 TO 85	ACTIVE	0.59	20	Check stock or order
SN74LVCZ240ANSR	<u>NS</u>	20	-40 TO 85	OBSOLETE			
SN74LVCZ240APW	<u>PW</u>	20	-40 TO 85	OBSOLETE			
SN74LVCZ240APWR	<u>PW</u>	20	-40 TO 85	ACTIVE	0.59	2000	Check stock or order

Table Data Updated on: 11/17/2000